ESI - PR3800 - FLUSH DIAPHRAGM PRESSURE SENSOR

PR3800-0001BG 4-20mA, 0..1 bar, Tri-clover 1.5", DIN

- Thick film sensor technology for long service life
- Pressure ranges up to 400 bar
- Up to 250°C media temperature option
- Easy clean flush membrane to prevent clogging





PRODUCT DESCRIPTION

Robustly constructed from stainless steel, the PR3800 series incorporates the latest strain gauge technology together with a custom IC amplifier offering excellent stability and accuracy over a long service life. The range offers a stable and accurate output signal of 4-20 mA with options for 0-5 V and 0-10 V. Typical applications include food processing, pharmaceutical, petrochemical, waste water and slurry handling. In these installations the process media may corrode the sensing diaphragm or clog the narrow pressure inlet on a standard transmitter. The flush membrane can be easily cleaned for long term reliability and outstanding performance. For hygienic applications the PR3800 series provides a sanitary grade pressure fitting. Seals are available in a variety of forms and materials for a wide range of applications and can be directly attached to the proposed connection or remotely via stainless steel capillary. Pressure ranges available from 0-200 mbar to

An optional ATEX and IECEx approved versions of this range are available for explosion protection for flammable gases (zone 0), dusts (zone 20) and mining areas (group I M1).

TECHNICAL DATA

| Ambient temperature | -2085°C |
|--------------------------|--------------------------|
| Approvals | CE, IEC |
| Electrical connection | DIN A 43650 |
| EMC | EN61000-6-4, EN61000-6-2 |
| Linearity | ≤±0.3% BSFL |
| Material of wetted parts | Stainless steel |
| Media temperature | -2085°C |
| Output | 4-20 mA |
| Overpressure protection | 1.5 bar |
| Pressure range max | 1 bar |
| | |

| Pressure range min | 0 bar |
|---------------------|---|
| | |
| Pressure reference | Gauge |
| | |
| Process connection | "Pipe clamp (tri-clover) 1.5""" |
| Sensor technology | Ceramic thick film or Isolated Piezoresistive Silicon |
| Concor tournology | Coramio and thin or located 1 local colours of moon |
| Storage temperature | 5.40°C |
| | 0.10 |
| Supply voltage | 13-36 V DC |
| ouppiy voitage | 10-00 V DO |